

1. (a) The common-base and common-emitter current gains is given by

$$\begin{aligned}\alpha_0 &= \gamma\alpha_T = 0.997 \times 0.998 = 0.995 \\ \beta_0 &= \frac{\alpha_0}{1 - \alpha_0} = \frac{0.995}{1 - 0.995} \\ &= 199 .\end{aligned}$$

- (b) Since $I_B = 0$ and $I_{Cp} = 10 \times 10^{-9}$ A , then I_{CBO} is 10×10^{-9} A . The emitter current is

$$\begin{aligned}I_{CEO} &= (1 + \beta_0)I_{CBO} \\ &= (1 + 199) \cdot 10 \times 10^{-9} \\ &= 2 \times 10^{-6} \text{ A} .\end{aligned}$$

2. For an ideal transistor,

$$\begin{aligned}\alpha_0 &= \gamma = 0.999 \\ \beta_0 &= \frac{\alpha_0}{1 - \alpha_0} = 999 .\end{aligned}$$

I_{CBO} is known and equals to 10×10^{-6} A . Therefore,

$$\begin{aligned}I_{CEO} &= (1 + \beta_0)I_{CBO} \\ &= (1 + 999) \cdot 10 \times 10^{-6} \\ &= 10 \text{ mA} .\end{aligned}$$